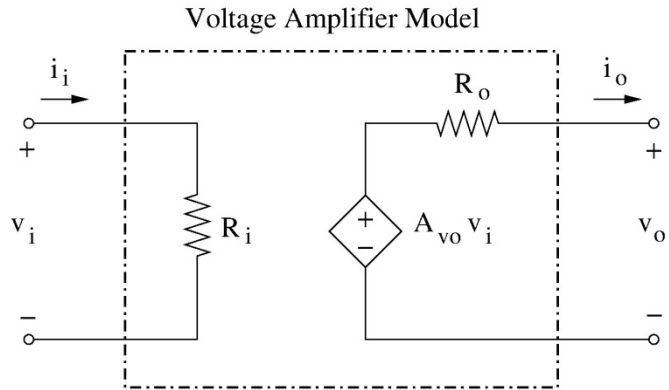


3. Fundamental amplifier configurations & Elementary R forms

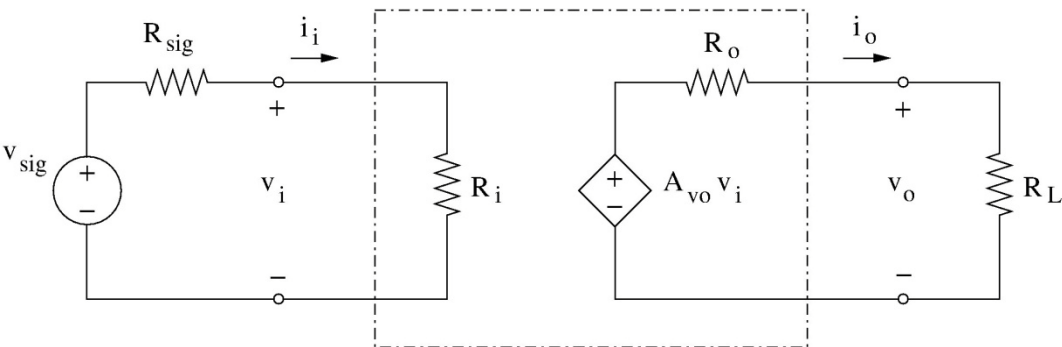
Sedra & Smith Sec. 5.6

(S&S 5th Ed: Sec. 4.7)

Voltage Amplifier Model



Input Resistance: $R_i = v_i / i_i$
Voltage gain: $A_v = v_o / v_i$ with load
Open-loop gain: $A_{vo} = v_o / v_i$ with no load
Output resistance: R_o (resistance seen between output terminals with $v_i = 0$)



$$\frac{v_i}{v_{sig}} = \frac{R_i}{R_i + R_{sig}}$$

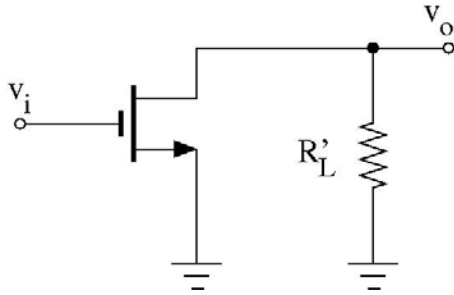
$$\frac{v_o}{v_i} = A_v = A_{vo} \cdot \frac{R_L}{R_L + R_o}$$

$$\frac{v_o}{v_{sig}} = \frac{R_i}{R_i + R_{sig}} \cdot A_{vo} \cdot \frac{R_L}{R_L + R_o}$$

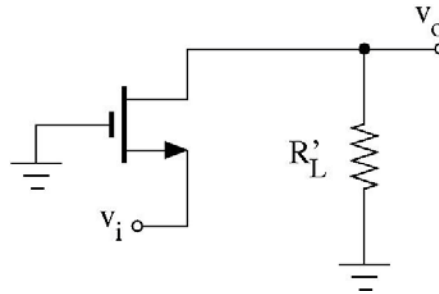
Fundamental MOS Amplifier Configurations

- We are considering **only signal circuit here!**
- There are only **FOUR single-transistor** MOS Amplifier Configuration

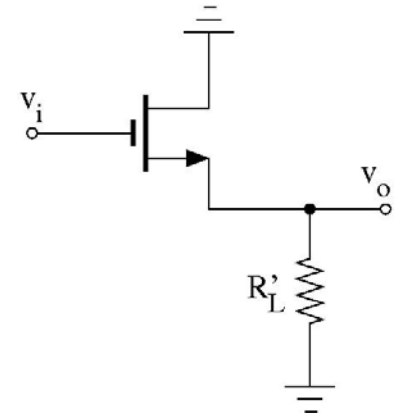
Possible MOS amplifier configurations



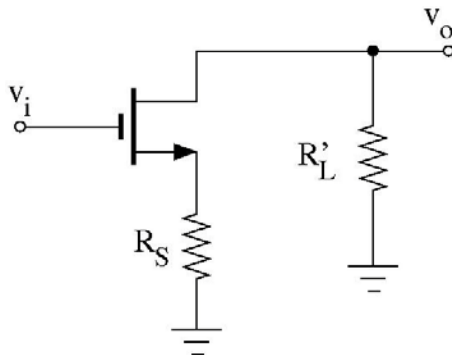
Common-Source



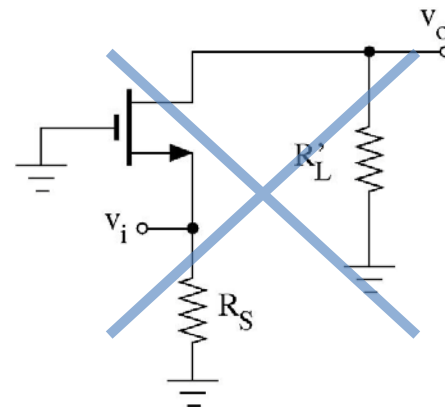
Common-Gate



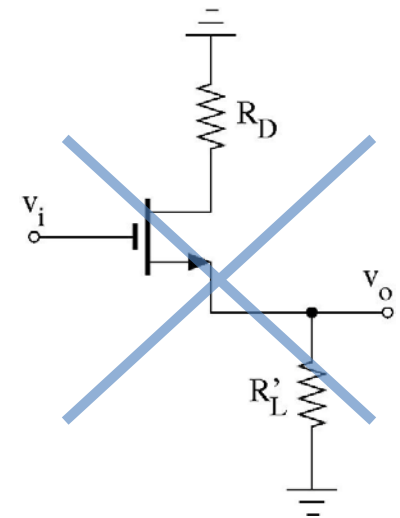
Common-Drain



Common-Source with R_S

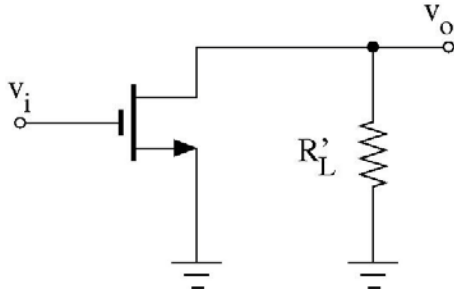


Same as Common Gate
(v_i does not change)

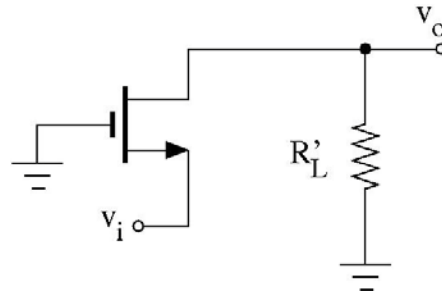


Not Useful

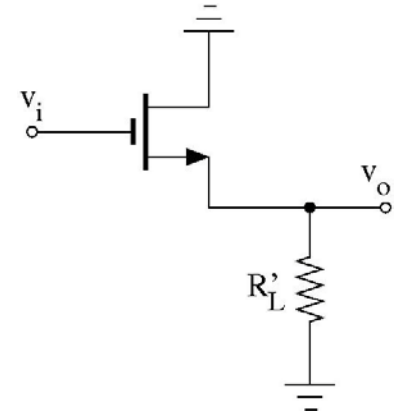
PMOS configurations are the same as NMOS



Common-Source

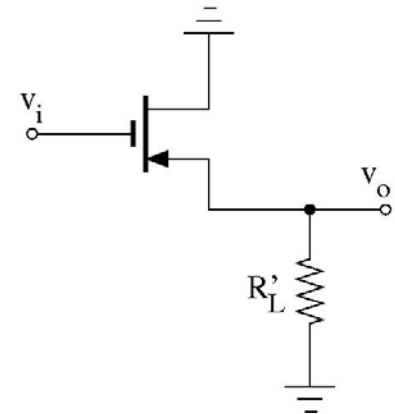
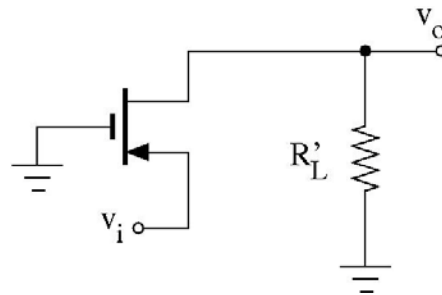
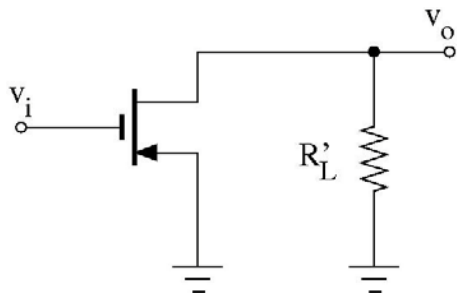


Common-Gate



Common-Drain

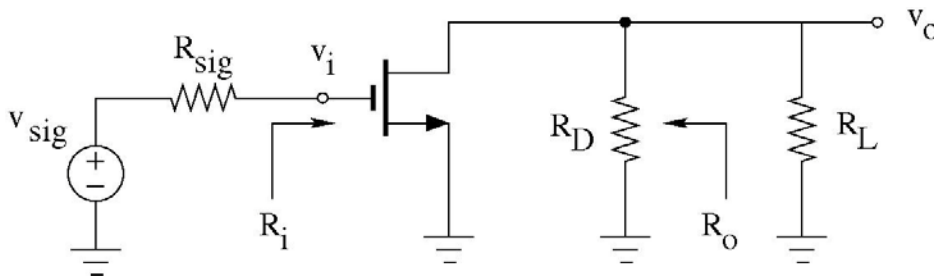
Since PMOS has the same signal model, configurations and results are exactly the same



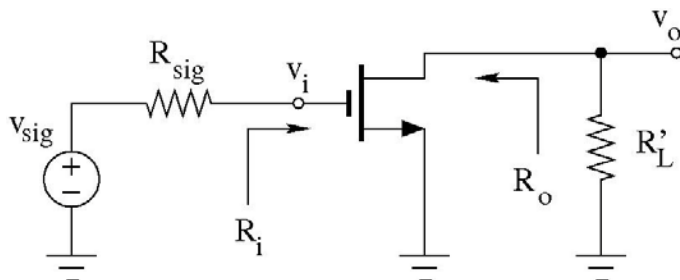
Textbook includes R_D in its analysis

Small Signal Circuit for a Common Source Amplifier

Textbook:



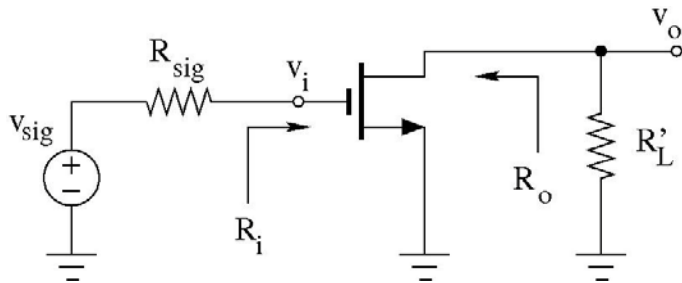
Lecture:



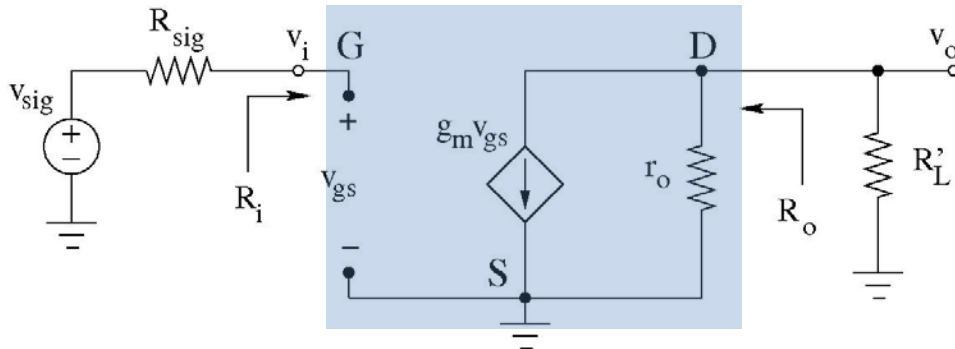
- Textbook is inconsistent. It includes R_D for common source and common gate but does not include R_S in common drain.
- Note R_D is parallel to R_L .
- **To avoid confusion, I am using only one resistor, R'_L , which is the equivalent of all resistors in the drain circuit (e.g., for the above circuit, $R'_L = R_L || R_D$)**

Common Source Configuration (Gain)

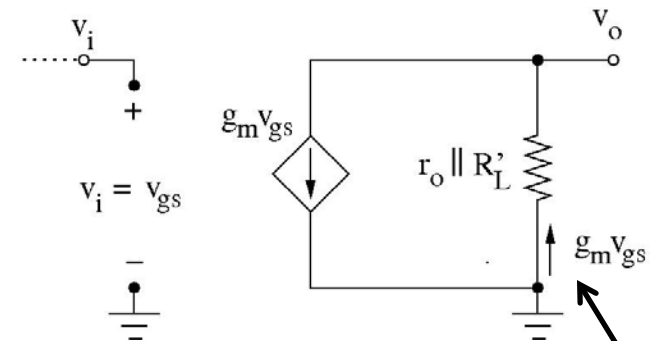
Signal Circuit:



Small Signal Circuit
with MOS SSM



Relevant circuit for
Gain calculation



By KCL

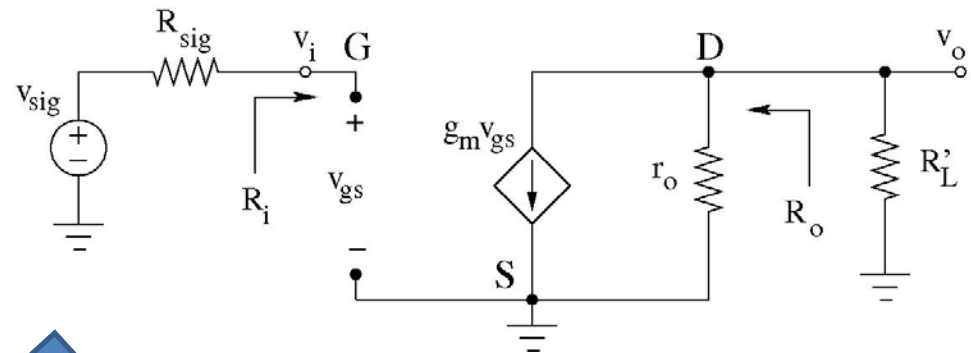
$$v_o = -g_m v_{gs} (r_o \parallel R'_L)$$

$$A_v = \frac{v_o}{v_i} = -g_m (r_o \parallel R'_L)$$

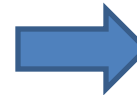
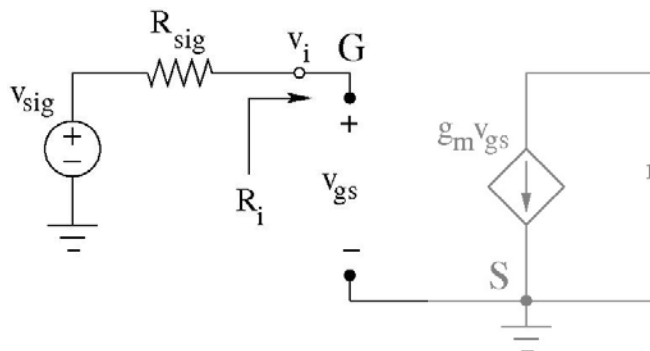
$$A_{vo} = -g_m r_o$$

Common Source Configuration (R_i)

Small Signal Circuit
with MOS SSM



Relevant circuit for
 R_i calculation

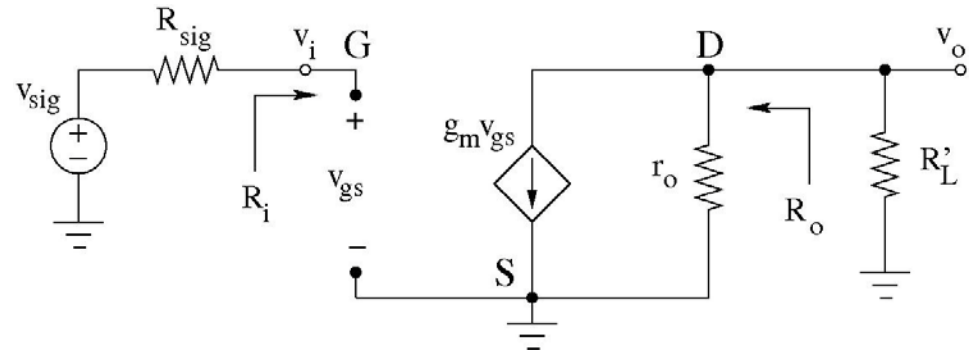


$$i_i = 0$$

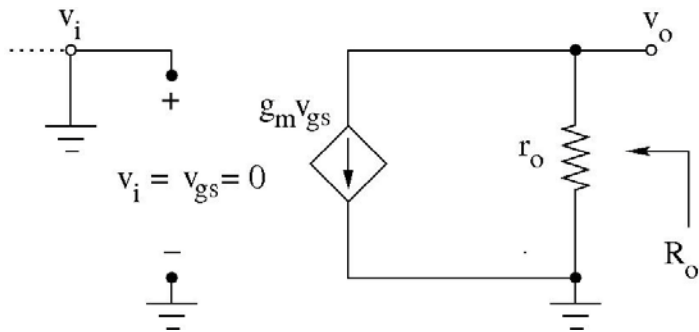
$$R_i = \frac{v_i}{i_i} = \infty$$

Common Source Configuration (R_o)

Small Signal Circuit
with MOS SSM



Relevant circuit for
 R_o calculation (set $v_i = 0$)

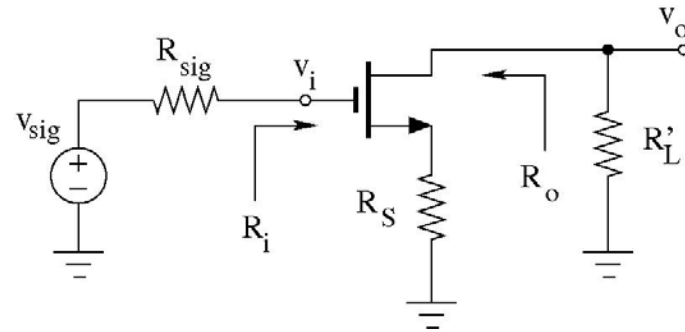


Current source becomes open circuit

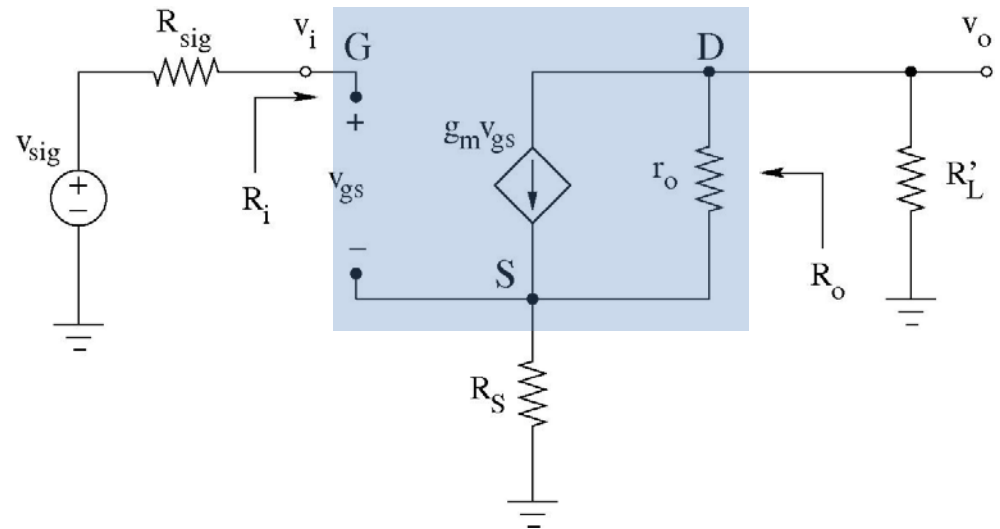
$$R_o = r_o$$

Common Source with Source Resistor

Signal Circuit:



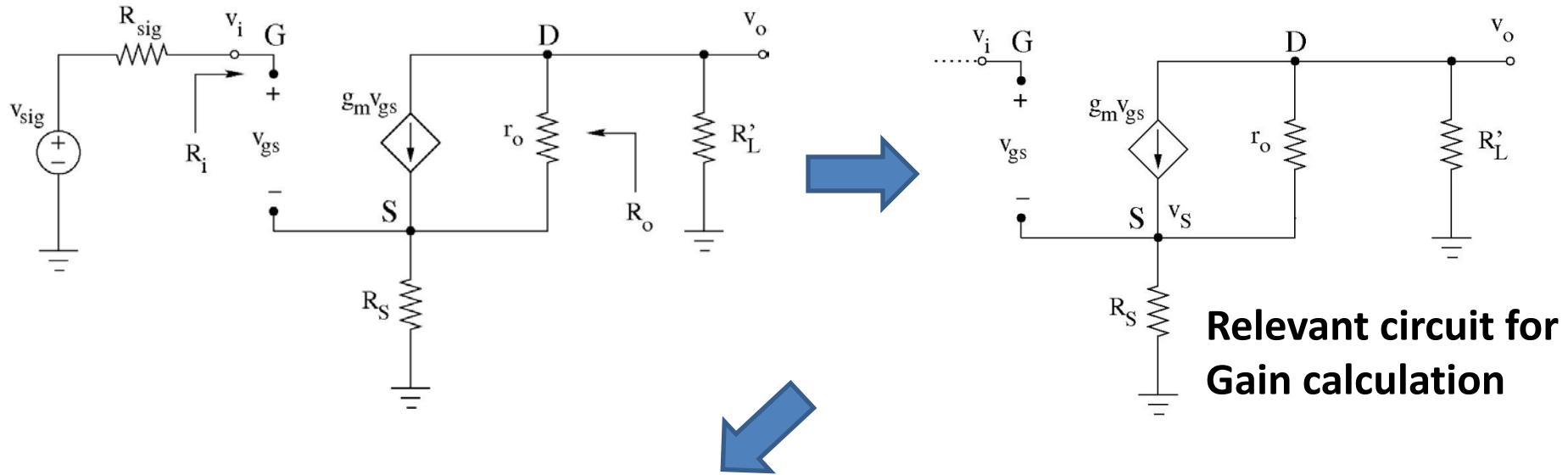
Small Signal Circuit
with MOS SSM



Input Resistance

$$i_i = 0 \Rightarrow R_i = \frac{v_i}{i_i} = \infty$$

Common Source with Source Resistor (Gain*)



Node voltage method:

$$v_{gs} = v_i - v_S$$

Node v_S
$$\frac{v_S}{R_S} + \frac{v_S - v_o}{r_o} - g_m(v_i - v_S) = 0$$

Node v_o
$$\frac{v_o}{R'_L} + \frac{v_o - v_S}{r_o} + g_m(v_i - v_S) = 0$$

$$A_v = \frac{v_o}{v_i} = - \frac{g_m r_o R'_L}{r_o + (1 + g_m r_o) R_S + R'_L}$$

$$A_v \approx - \frac{g_m R'_L}{1 + g_m R_S + R'_L / r_o}$$

$$A_{v_o} = -g_m r_o$$

* Text book ignore r_o

Common Source with Source Resistor (R_o^*)

- set $v_i = 0$
- Attach v_x and compute i_x
- $R_o = v_x / i_x$

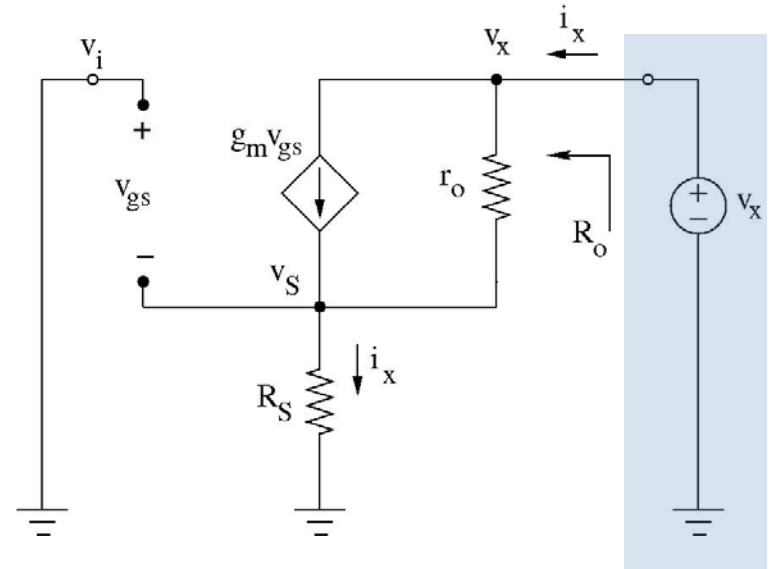
Node voltage method:

$$v_{gs} = -v_S$$

Node v_S
$$\frac{v_S}{R_S} + \frac{v_S - v_x}{r_o} - g_m(-v_S) = 0$$

$$\frac{v_S}{R_S} = \frac{v_x}{r_o + (1 + g_m r_o) R_S}$$

$$i_x = \frac{v_S}{R_S} = \frac{v_x}{r_o + (1 + g_m r_o) R_S}$$



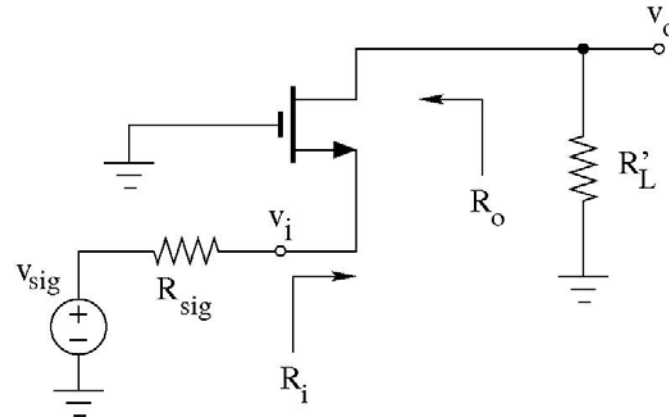
$$\frac{1}{R_o} \equiv \frac{i_x}{v_x} = \frac{1}{r_o + (1 + g_m r_o) R_S}$$

$$R_o = r_o + (1 + g_m r_o) R_S$$

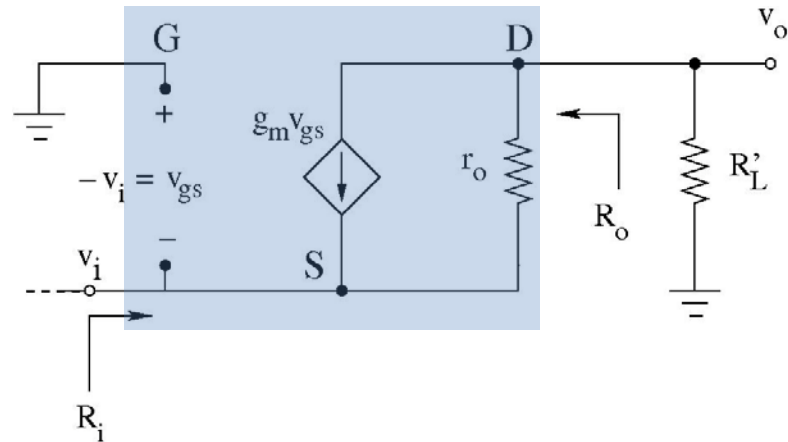
* Text book ignore r_o

Common Gate Configuration

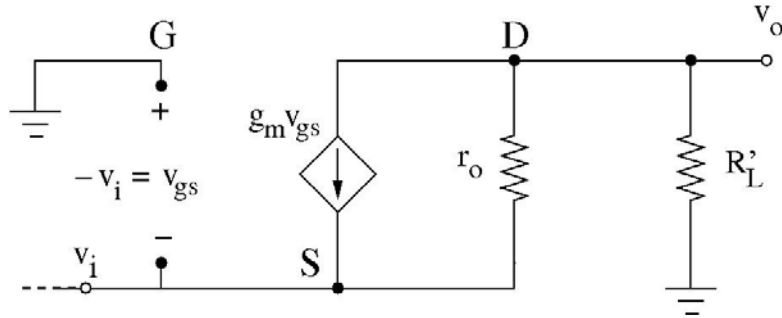
Signal Circuit:



Small Signal Circuit with MOS SSM



Common Gate Configuration (Gain*)



Node voltage method:

$$v_{gs} = -v_i$$

Node v_o

$$\frac{v_o}{R'_L} + \frac{v_o - v_i}{r_o} + g_m(-v_i) = 0$$

$$\frac{v_o}{r_o \parallel R'_L} = \frac{1 + g_m r_o}{r_o} v_i$$

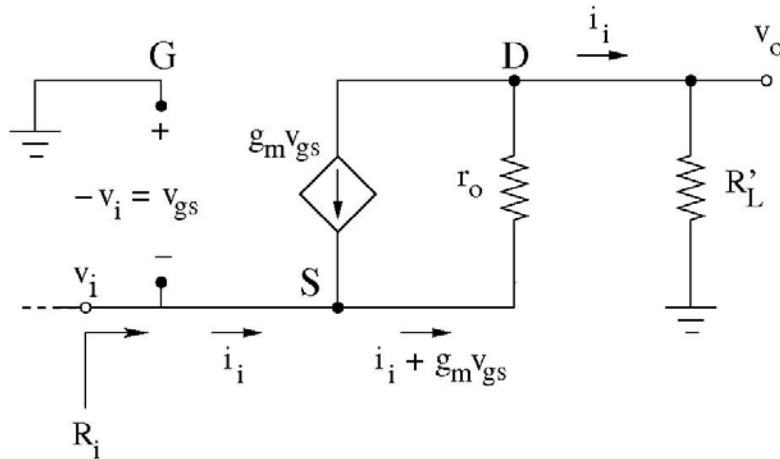
$$A_v = \frac{v_o}{v_i} = \frac{1 + g_m r_o}{r_o} (r_o \parallel R'_L)$$

$$A_v \approx g_m (r_o \parallel R'_L)$$

$$A_{vo} \approx g_m r_o$$

Common Gate Configuration (R_i and R_o^*)

Input Resistance

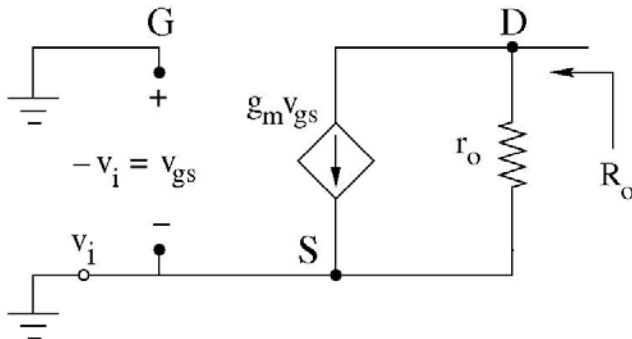


KVL: $v_i = (i_i + g_m v_{gs})r_o + i_i R'_L$
 $v_i(1 + g_m r_o) = i_i(r_o + R'_L)$

$$R_i = \frac{v_i}{i_i} = \frac{r_o + R'_L}{1 + g_m r_o}$$

$$R_i \approx \frac{1}{g_m} + \frac{R'_L}{g_m r_o}$$

Output Resistance (set $v_i = 0$)

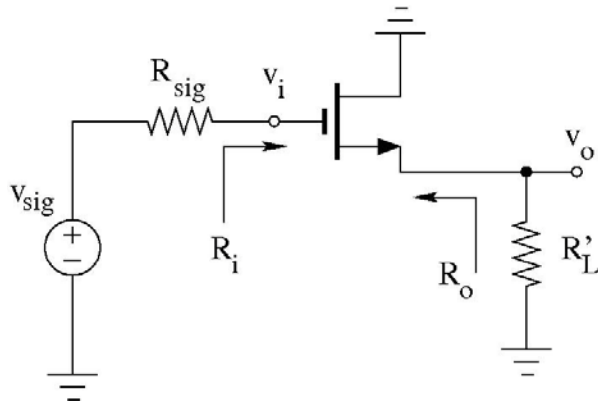


Current source becomes open circuit

$$R_o = r_o$$

* Text book ignore r_o

Common Drain Configuration (Source Follower)



Gain

Node voltage method:

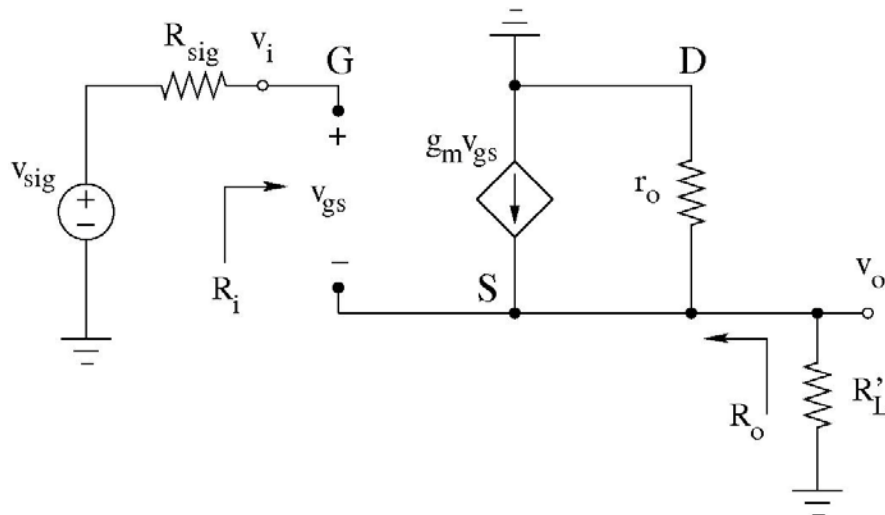
$$v_{gs} = v_i - v_o$$

Node v_o
$$\frac{v_o}{R'_L} + \frac{v_o}{r_o} - g_m(v_i - v_o) = 0$$

$$g_m v_i = \frac{v_o}{r_o \parallel R'_L} + g_m v_o$$

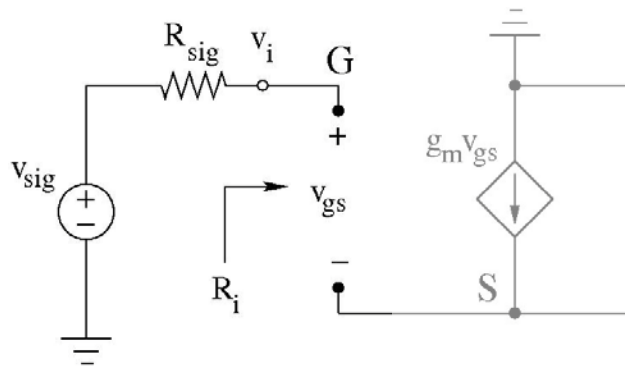
$$A_v = \frac{g_m(r_o \parallel R'_L)}{1 + g_m(r_o \parallel R'_L)}$$

$$A_{v_o} = \frac{g_m r_o}{1 + g_m r_o} \approx 1$$



Common Drain Configuration (Source Follower)

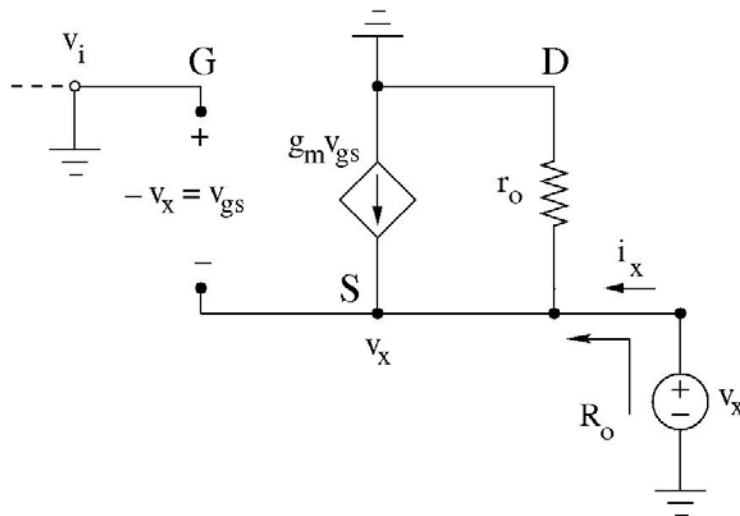
Input Resistance



$$i_i = 0$$

$$R_i = \frac{v_i}{i_i} = \infty$$

Output Resistance (set $v_i = 0$)



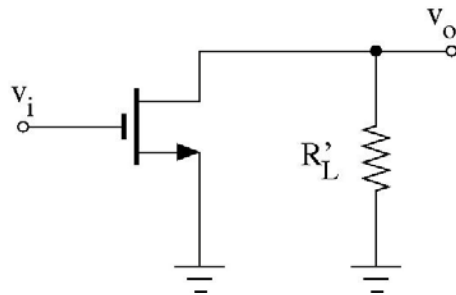
$$i_x = \frac{v_x}{r_o} - g_m v_{gs} = \frac{v_x}{r_o} + \frac{v_x}{1/g_m}$$

$$R_o = \frac{1}{g_m} \parallel r_o \approx \frac{1}{g_m}$$

MOS Fundamental Amplifier Configurations

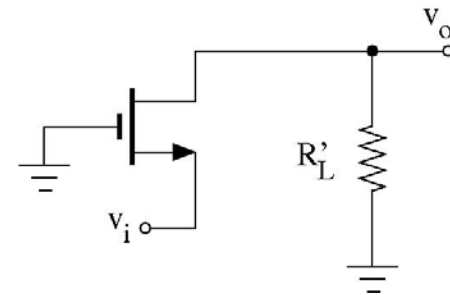
(PMOS circuits are identical)

Common Source



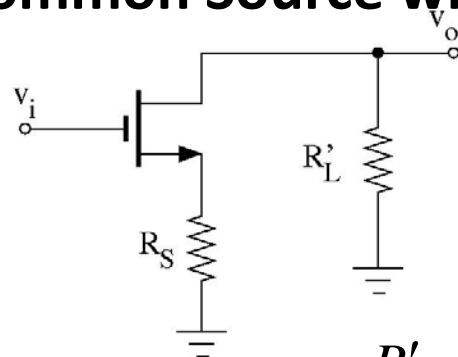
$$A_v = -g_m (r_o \parallel R'_L)$$

Common Gate



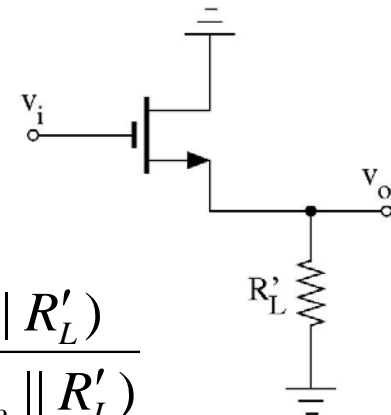
$$A_v = g_m (r_o \parallel R'_L)$$

Common Source with R_S



$$A_v = -\frac{g_m R'_L}{1 + g_m R_S + R'_L / r_o}$$

Common Drain/Source Follower

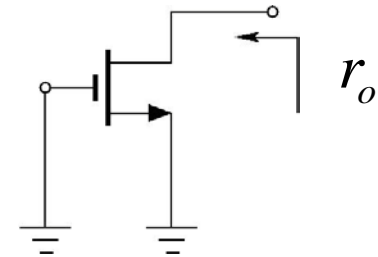
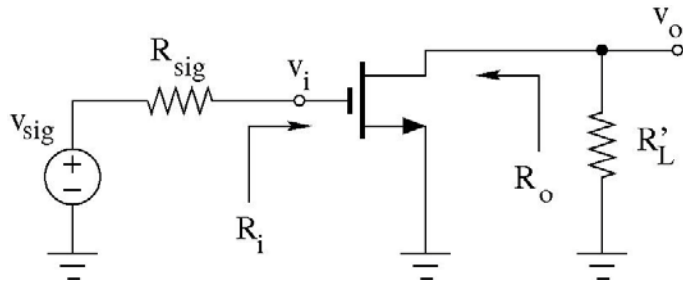


$$A_v = \frac{g_m (r_o \parallel R'_L)}{1 + g_m (r_o \parallel R'_L)}$$

Elementary R Forms

A Transistor can be configured to act as a resistor for small signals!

Ex: Output resistance of a **CS Amplifier**



Set $v_i = 0$, **current source** becomes **open circuit**

$$R_o = r_o$$

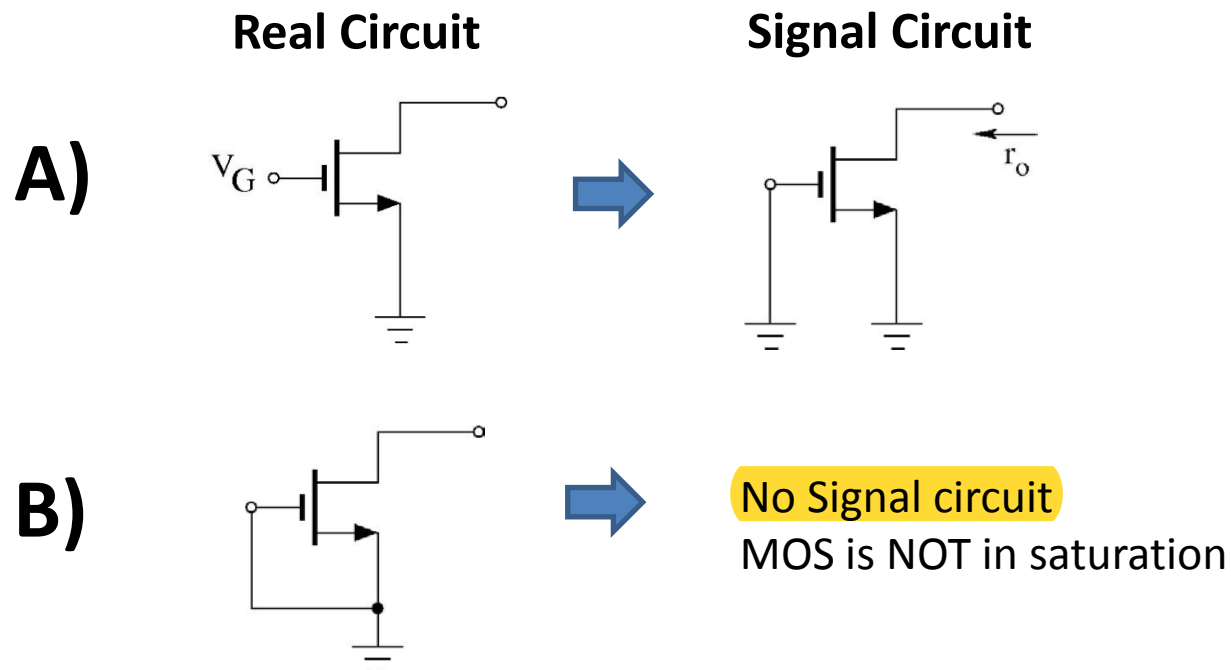
Notation:

r_o is the **small-signal resistance** between the point and ground

- If we connect any two terminals of a MOS, we get a two-terminal device.
 - For Small Signals, this two terminal device can be replaced with its Thevenin equivalent circuit.
 - As there is NO independent sources present, the Thevenin equivalent circuit is reduced to a resistor.

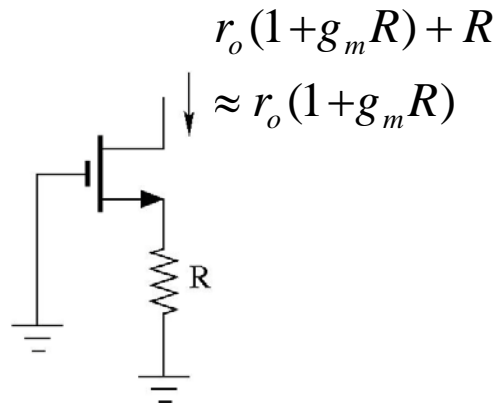
A Transistor can be configured to act as a resistor for small signals!

- But, MOS should be in saturation for small signal model to work!
 - Connection between MOS terminals are, therefore, made through ground for signals.
 - In fact, one or two MOS terminals have to be connected to bias power supply to ensure that MOS is in saturation (there is an exception, see next page)

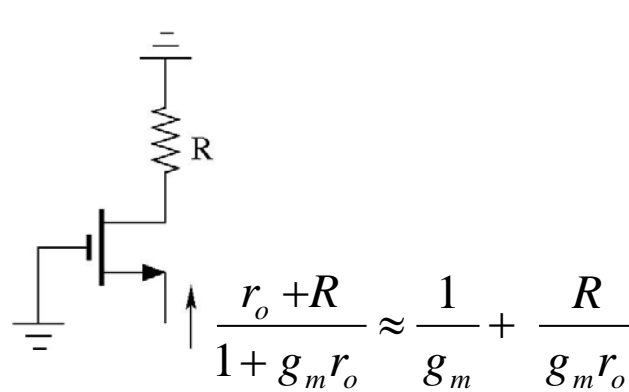
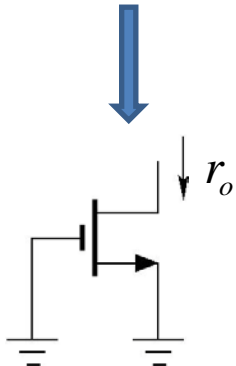


MOS Elementary R Forms

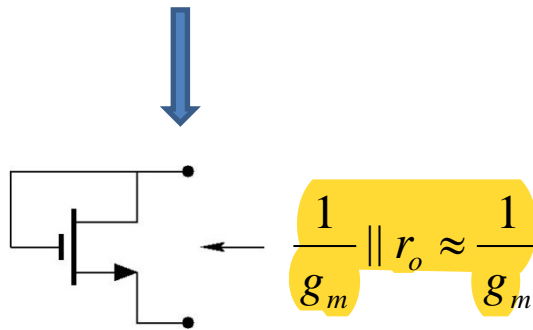
(PMOS circuits are identical)



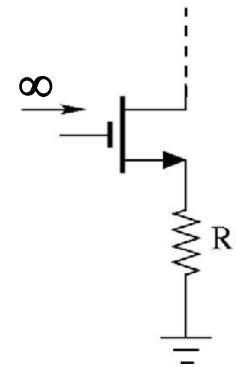
Output resistance
of **CS Amp** with R_s



Input resistance
of **CG Amp**



Diode-connected
Transistor
Always in saturation!



Input resistance
of **CS Amp**

Above configurations are for Small Signal. Typically one or both grounds are connected to bias voltage sources to ensure that MOS is in saturation!

**Gain, input, and output resistances of
MOS amplifiers can be found
using
fundamental amplifiers configurations
and elementary R forms**